

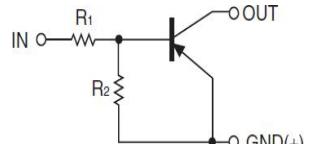


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MAITUO ELECTRONIC

DTA114Yx Digital Transistors (Built-in Resistors)

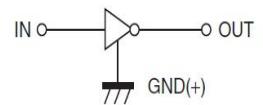
• Equivalent Circuit

DIGITAL TRANSISTOR (PNP)



FEATURES

- Built-in bias resistors enable the configuration of an inverter circuit without connecting external input resistors (see equivalent circuit)
- The bias resistors consist of thin-film resistors with complete isolation to allow negative biasing of the input. They also have the advantage of almost completely eliminating parasitic effects
- Only the on/off conditions need to be set for operation, making device design easy



PIN CONNECTIONS and MARKING

DTA114YE		SOT-523	DTA114YUA		SOT-323
		1. IN 2. GND 3. OUT			1. IN 2. GND 3. OUT
DTA114YKA		SOT-23-3L	DTA114YCA		SOT-23
		1. IN 2. GND 3. OUT			1. IN 2. GND 3. OUT

ORDERING INFORMATION

Part Number	MARKING	Package	Packing Method	Pack Quantity
DTA114YE	54	SOT-523	Reel	3000pcs/Reel
DTA114YUA	54	SOT-323	Reel	3000pcs/Reel
DTA114YKA	54	SOT-23-3L	Reel	3000pcs/Reel
DTA114YCA	54	SOT-23	Reel	3000pcs/Reel



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MAXIMUM RATINGS(Ta=25°C unless otherwise noted)

Symbol	Parameter	Limits(DTA114Y)						Unit
		M	E	UA	KA	CA	SA	
V _{cc}	Supply Voltage	-50						V
V _{IN}	Input Voltage	-40~+6						V
I _O	Output Current	-70						mA
I _{CM}	Peak Collector Current	-100						mA
P _D	Power Dissipation	100	150	200	200	200	300	mW
T _J ,T _{stg}	Operation Junction and Storage Temperature Range	-55~+150						°C

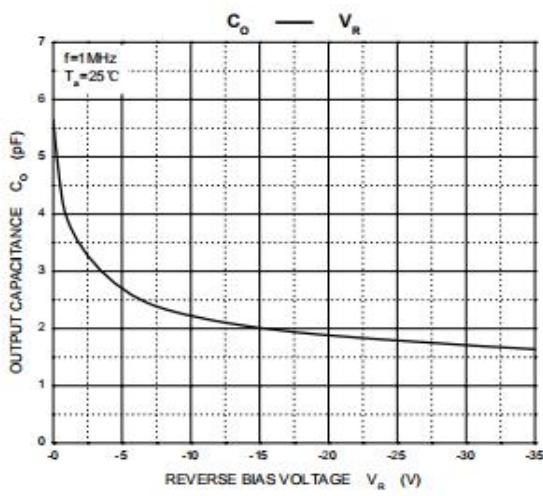
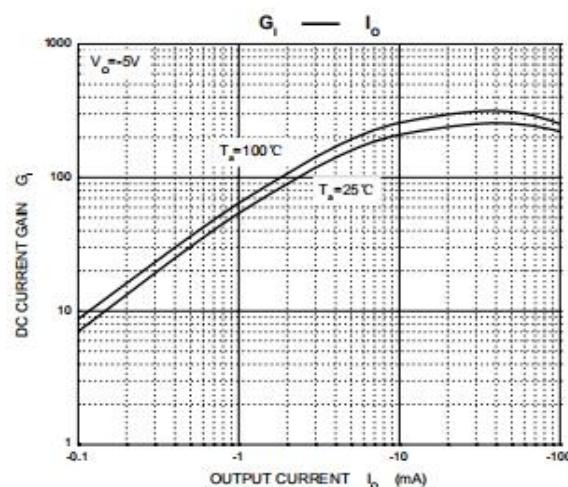
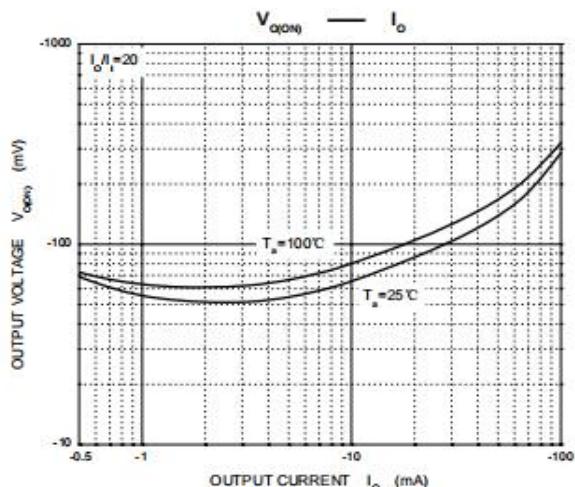
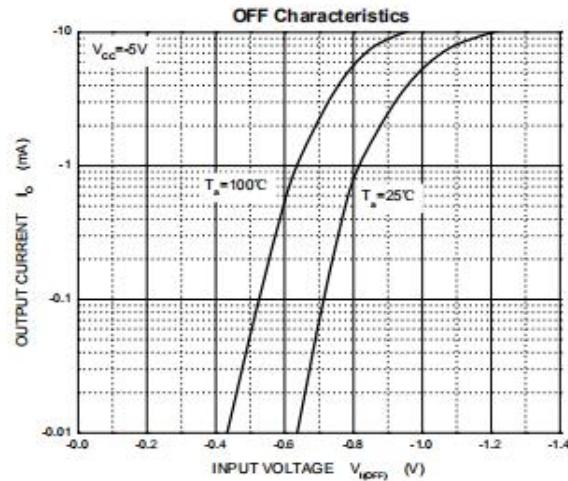
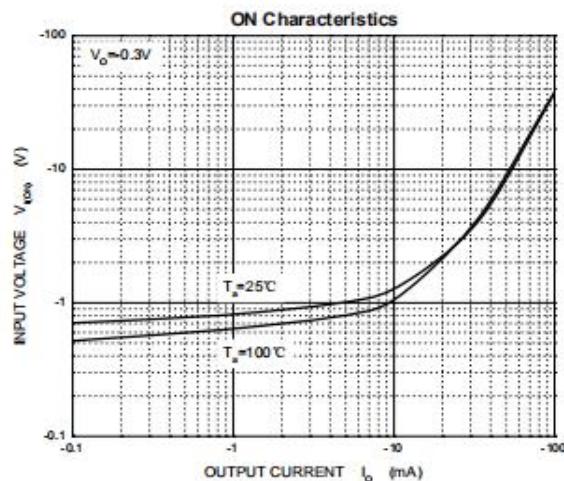
ELECTRICAL CHARACTERISTICS (Ta=25°C unless otherwise specified)

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Input voltage	V _{I(off)}	V _{CC} =-5V,I _O =-100μA	-0.3			V
	V _{I(on)}	V _O =-0.3V,I _O =-1 mA			-1.4	V
Output voltage	V _{O(on)}	I _O /I _I =-5mA/-0.25mA			-0.3	V
Input current	I _I	V _I =-5V			-0.88	mA
Output current	I _{O(off)}	V _{CC} =-50V,V _I =0			-0.5	μA
DC current gain	G _I	V _O =-5V,I _O =-5mA	68			z
Input resistance	R _I		7	10	13	kΩ
Resistance ratio	R ₂ /R _I		3.7	4.7	5.7	
Transition frequency	f _T	V _O =-10V,I _O =-5mA,f=100MHz		250		MHz

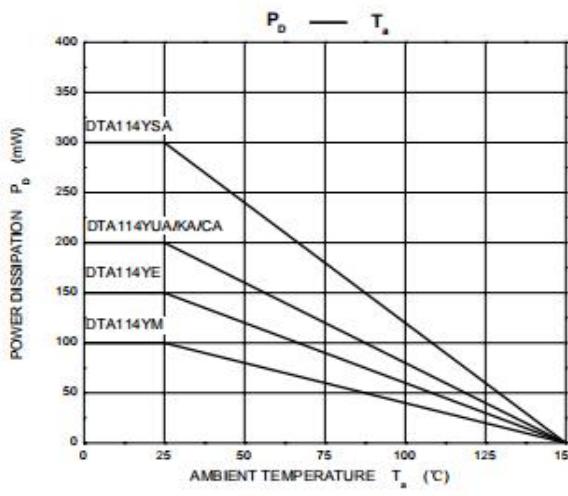


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Typical Characteristics



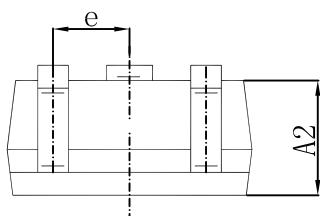
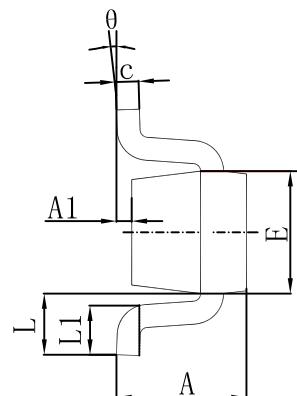
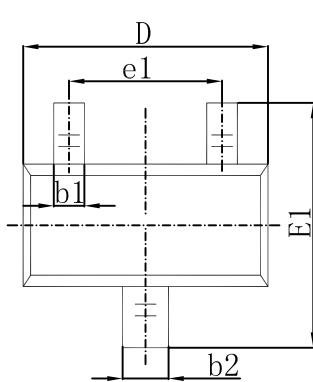
REVERSE VOLTAGE V_R (V) AMBIENT TEMPERATURE T_a ($^\circ\text{C}$)





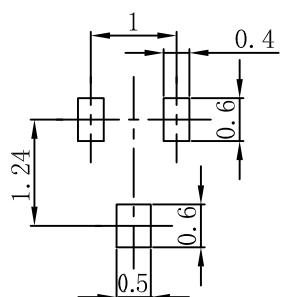
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SOT-523 Package Outline Dimensions



Symbol	Dimensions In Millimeters		Dimensions In Inches	
	Min.	Max.	Min.	Max.
A	0.700	0.900	0.028	0.035
A1	0.000	0.100	0.000	0.004
A2	0.700	0.800	0.028	0.031
b1	0.150	0.250	0.006	0.010
b2	0.250	0.350	0.010	0.014
c	0.100	0.200	0.004	0.008
D	1.500	1.700	0.059	0.067
E	0.700	0.900	0.028	0.035
E1	1.450	1.750	0.057	0.069
e	0.500 TYP.		0.020 TYP.	
e1	0.900	1.100	0.035	0.043
L	0.400 REF.		0.016 REF.	
L1	0.260	0.460	0.010	0.018
θ	0°	8°	0°	8°

SOT-523 Suggested Pad Layout



Note:

1. Controlling dimension:in millimeters.
2. General tolerance: $\pm 0.05\text{mm}$.
3. The pad layout is for reference purposes only.